

Single, Dual, and Quad Micropower, Low Drift, RRIO Operational Amplifiers

ISL28130, ISL28230, ISL28430

The ISL28130, ISL28230 and ISL28430 are single, dual and quad micropower, low offset drift operational amplifiers that are optimized for single and dual supply operation from 1.65V to 5.5V and $\pm 0.825\text{V}$ to $\pm 2.75\text{V}$. Their low supply current of $20\mu\text{A}$ and rail-to-rail input/output enable the ISL28130, ISL28230, ISL28430 to be an excellent general purpose op amp for a range of applications. The ISL28130, ISL28230 and ISL28430 are ideal for handheld devices that operate off 2 AA or single Li-ion batteries.

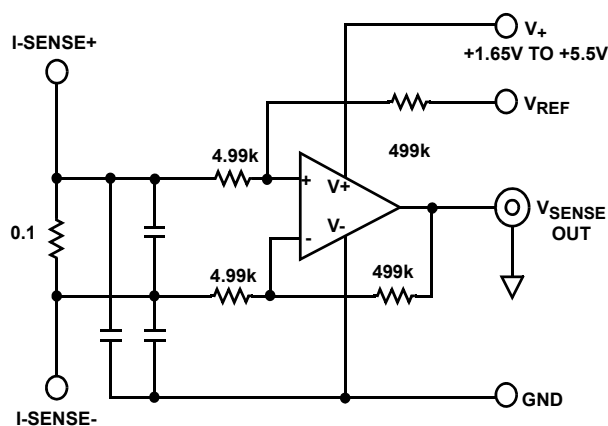
The ISL28130 is available in industry standard pinouts for 5 Ld SOT-23, 5 Ld SC70 and 8 Ld SOIC packages. The ISL28230 is available in industry standard pinouts for 8 Ld MSOP, 8 Ld SOIC and 8 Ld DFN packages. The ISL28430 is available in 14 Ld TSSOP and 14 Ld SOIC packages. All devices operate over the temperature range of -40°C to $+125^\circ\text{C}$.

Features

- Low Input Offset Voltage $40\mu\text{V}$, Max.
- Low Offset Drift $150\text{nV}/^\circ\text{C}$, Max
- Input Bias Current 250pA , Max.
- Quiescent Current (Per Amplifier) $20\mu\text{A}$, Typ.
- Single Supply Range $+1.65\text{V}$ to $+5.5\text{V}$
- Dual Supply Range. $\pm 0.825\text{V}$ to $\pm 2.75\text{V}$
- Low Noise (0.01Hz to 10Hz) $1.1\mu\text{V}_{\text{P-P}}$, Typ.
- Rail-to-Rail Inputs and Output

Applications

- Bi-Directional Current Sense
- Temperature Measurement
- Medical Equipment
- Electronic Weigh Scales
- Precision/Strain Gauge Sensor
- Precision Regulation
- Low Ohmic Current Sense
- High Gain Analog Front Ends



BI-DIRECTIONAL CURRENT SENSE AMPLIFIER

FIGURE 1. TYPICAL APPLICATION DIAGRAM

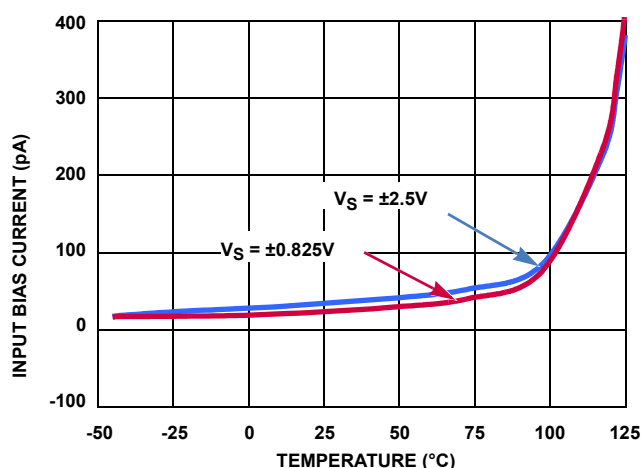


FIGURE 2. I_B vs TEMPERATURE

ISL28130, ISL28230, ISL28430

Ordering Information

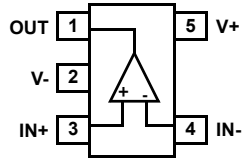
PART NUMBER (Notes 3, 4)	PART MARKING	TEMP RANGE (°C)	TEMPERATURE GRADE	PACKAGE (Pb-Free)	PKG. DWG. #
ISL28130CHZ-T7 (Note 2)	BDPA (Note 5)	0 to +70	Commercial	5 Ld SOT-23	P5.064A
ISL28130CHZ-T7A (Note 2)	BDPA (Note 5)	0 to +70	Commercial	5 Ld SOT-23	P5.064A
ISL28130FHZ-T7 (Note 2)	BEFA (Note 5)	-40 to +125	Full	5 Ld SOT-23	P5.064A
ISL28130FHZ-T7A (Note 2)	BEFA (Note 5)	-40 to +125	Full	5 Ld SOT-23	P5.064A
ISL28130CEZ-T7 (Note 2)	BLA (Note 5)	0 to +70	Commercial	5 Ld SC-70	P5.049
ISL28130CEZ-T7A (Note 2)	BLA (Note 5)	0 to +70	Commercial	5 Ld SC-70	P5.049
ISL28130FEZ-T7 (Note 2)	BNA (Note 5)	-40 to +125	Full	5 Ld SC-70	P5.049
ISL28130FEZ-T7A (Note 2)	BNA (Note 5)	-40 to +125	Full	5 Ld SC-70	P5.049
ISL28130CBZ (Note 1)	28130 CBZ	0 to +70	Commercial	8 Ld SOIC	M8.15E
ISL28130FBZ (Note 1) <i>Coming Soon</i>	28130 FBZ	-40 to +125	Full	8 Ld SOIC	M8.15E
ISL28230CUZ (Note 1)	8230Z	0 to +70	Commercial	8 Ld MSOP	M8.118A
ISL28230FUZ (Note 1)	8230F	-40 to +125	Full	8 Ld MSOP	M8.118A
ISL28230CBZ (Note 1)	28230 CBZ	0 to +70	Commercial	8 Ld SOIC	M8.15E
ISL28230FBZ (Note 1)	28230 FBZ	-40 to +125	Full	8 Ld SOIC	M8.15E
ISL28230CRZ (Note 1)	230Z	0 to +70	Commercial	8 Ld 3mmx3mm DFN	L8.3x3J
ISL28230FRZ (Note 1) <i>Coming Soon</i>	230F	-40 to +125	Full	8 Ld 3mmx3mm DFN	L8.3x3J
ISL28430CBZ (Note 1)	28430 CBZ	0 to +70	Commercial	14 Ld SOIC	MDP0027
ISL28430FBZ (Note 1)	28430 FBZ	-40 to +125	Full	14 Ld SOIC	MDP0027
ISL28430CVZ (Note 1)	28430 CVZ	0 to +70	Commercial	14 Ld TSSOP	MDP0044
ISL28430FVZ (Note 1)	28430 FVZ	-40 to +125	Full	14 Ld TSSOP	MDP0044

NOTES:

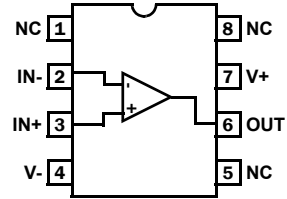
1. Add "-T*" suffix for tape and reel. Please refer to [TB347](#) for details on reel specifications.
2. Only available in tape and reel. Please refer to [TB347](#) for details on reel specifications.
3. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
4. For Moisture Sensitivity Level (MSL), please see device information page for [ISL28130](#), [ISL28230](#), [ISL28430](#). For more information on MSL please see techbrief [TB363](#).
5. The part marking is located on the bottom of the part.

Pin Configurations

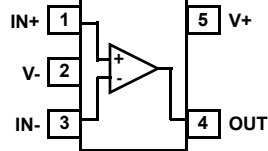
ISL28130
(5 LD SOT-23)
TOP VIEW



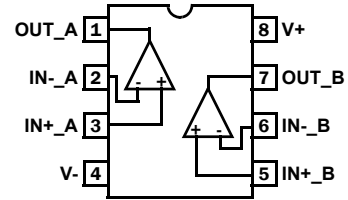
ISL28130
(8 LD SOIC)
TOP VIEW



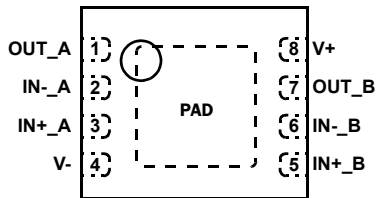
ISL28130
(5 LD SC-70)
TOP VIEW



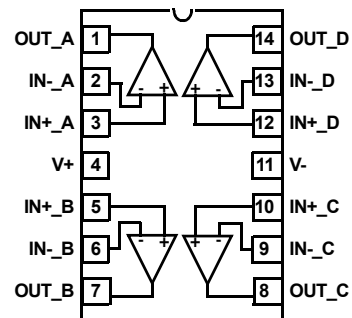
ISL28230
(8 LD MSOP, SOIC)
TOP VIEW



ISL28230
(8 LD DFN)
TOP VIEW

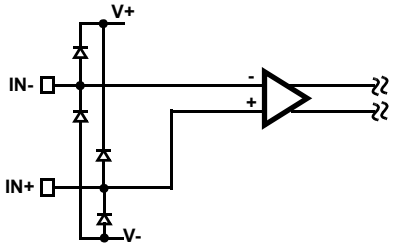
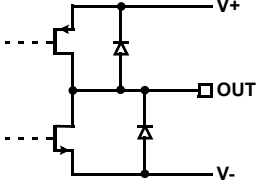


ISL28430
(14 LD TSSOP, SOIC)
TOP VIEW



ISL28130, ISL28230, ISL28430

Pin Descriptions

ISL28130 (5 Ld SOT-23)	ISL28130 (8 Ld SOIC)	ISL28130 (5 LD SC-70)	ISL28230 (8 Ld MSOP, SOIC, DFN)	ISL28430 (14 Ld TSSOP, SOIC)	PIN NAME	FUNCTION	EQUIVALENT CIRCUIT
3	3	1	3 5 - -	3 5 10 12	IN+ IN+_A IN+_B IN+_C IN+_D	Non-inverting input	 Circuit 1
2	4	2	4	11	V-	Negative supply	
4	2	3	2 6 - -	2 6 9 13	IN- IN-_A IN-_B IN-_C IN-_D	Inverting input	(See "Circuit 1")
1	6	4	1 7 - -	1 7 8 14	OUT OUT_A OUT_B OUT_C OUT_D	Output	 Circuit 2
5	7	5	8	4	V+	Positive supply	
-	1, 5, 8	-	-	-	NC	Not Connected – This pin is not electrically connected internally.	
-	-	-	PAD	-	Paddle	Thermal Pad. Connect to most negative supply. DFN packages only.	

ISL28130, ISL28230, ISL28430

Absolute Maximum Ratings

Max Supply Voltage V_+ to V_-	6.5V
Max Voltage V_{IN} to GND	($V_- - 0.3V$) to ($V_+ + 0.3V$)V
Max Input Differential Voltage	6.5V
Max Input Current	20mA
Max Voltage V_{OUT} to GND (10s)	$\pm 3.0V$
ESD Tolerance (ISL28130)	
Human Body Model (Tested at JESD22-A114F)	3000V
Machine Model (Tested at JESD22-A115B)	200V
Charged Device Model (Tested at JESD22-C110D)	1500V
ESD Tolerance (ISL28230, ISL28430)	
Human Body Model (Tested at JESD22-A114F)	4000V
Machine Model (Tested at JESD22-A115B)	400V
Charged Device Model (Tested at JESD22-C110D)	2000V
Latch-Up Passed Per JESD78B	+125°C

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
5 Ld SOT-23 (Notes 6, 8)	225	110
5 Ld SC70 (Notes 6, 8)	206	146
8 Ld SOIC (ISL28130) (Notes 6, 8)	135	95
8 Ld MSOP (Notes 6, 8)	180	65
8 Ld SOIC (ISL28230) (Notes 6, 8)	125	90
8 Ld DFN (Notes 7, 9)	53	12
14 Ld TSSOP (Notes 6, 8)	110	40
14 Ld SOIC (Notes 6, 8)	75	47
Maximum Storage Temperature Range	-65°C to +150°C	
Pb-Free Reflow Profile	see link below http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

Operating Conditions

Temperature Range	
Full Grade Devices	-40°C to +125°C
Commercial Grade Devices	0°C to +70°C

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief TB379 for details.
- θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief [TB379](#).
- For θ_{JC} , the "case temp" location is taken at the package top center.
- For θ_{JC} , the "case temp" location is the center of the exposed metal pad on the package underside.

Electrical Specifications $V_+ = 5V$, $V_- = 0V$, $V_{CM} = 2.5V$, $T_A = +25^\circ C$, $R_L = 10k\Omega$, unless otherwise specified. **Boldface limits apply over the entire operating temperature range.**

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNIT
DC SPECIFICATIONS						
V_{OS}	Input Offset Voltage	$V_S = 1.65V$ to $5.5V$	-40	± 5	40	μV
		$V_S = 1.65V$ to $5.5V$; $T = 0^\circ C$ to $+70^\circ C$	-46.8	-	46.8	μV
		$V_S = 1.65V$ to $5.5V$; $T = -40^\circ C$ to $+125^\circ C$	-55	-	55	μV
TCV_{OS}	Input Offset Voltage Temperature Coefficient		-150	20	150	nV/°C
I_{OS}	Input Offset Current		-	-60	-	pA
TCI_{OS}	Input Offset Current Temperature Coefficient		-	0.11	-	pA/°C
I_B	Input Bias Current	$T = 0^\circ C$ to $+70^\circ C$	-250	-	250	pA
		$T = -40^\circ C$ to $+125^\circ C$	-700	-	700	pA
Common Mode Input Voltage Range		Guaranteed by CMRR	-0.1	-	5.1	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = -0.1V$ to $5.1V$	110	125	-	dB
			105	-	-	dB
PSRR	Power Supply Rejection Ratio	$V_S = 2.0V$ to $5.5V$	105	138	-	dB
			105	-	-	dB
V_{OH}	Output Voltage Swing, High		4.950	4.981	-	V
V_{OL}	Output Voltage Swing, Low		-	18	50	mV

ISL28130, ISL28230, ISL28430

Electrical Specifications $V_+ = 5V$, $V_- = 0V$, $V_{CM} = 2.5V$, $T_A = +25^\circ C$, $R_L = 10k\Omega$, unless otherwise specified. **Boldface limits apply over the entire operating temperature range. (Continued)**

PARAMETER	DESCRIPTION	CONDITIONS	MIN (Note 10)	TYP	MAX (Note 10)	UNIT
A_{OL}	Open Loop Gain	$R_L = 1M\Omega$	-	150	-	dB
V_+	Supply Voltage	Guaranteed by V_{OS}	1.65	-	5.5	V
I_S	Supply Current, Per Amplifier	$R_L = OPEN$	-	20	25	μA
			-	-	35	μA
I_{SC+}	Output Source Short Circuit Current	$R_L = \text{Short } V_-$	-	15	-	mA
I_{SC-}	Output Sink Short Circuit Current	$R_L = \text{Short } V_+$	-	-15	-	mA
AC SPECIFICATIONS						
GBWP	Gain Bandwidth Product	$A_V = 100$, $R_F = 100k\Omega$, $R_G = 1k\Omega$, $R_L = 10k\Omega$ to V_{CM}	-	400	-	kHz
$e_N V_{P-P}$	Peak-to-Peak Input Noise Voltage	$f = 0.01Hz$ to $10Hz$	-	1.1	-	μV_{P-P}
e_N	Input Noise Voltage Density	$f = 1kHz$	-	65	-	$nV/\sqrt{Hz}$
i_N	Input Noise Current Density	$f = 1kHz$	-	72	-	$fA/\sqrt{Hz}$
		$f = 10Hz$	-	80	-	$fA/\sqrt{Hz}$
C_{in}	Differential Input Capacitance	$f = 1MHz$	-	1.6	-	pF
	Common Mode Input Capacitance		-	1.12	-	pF
TRANSIENT RESPONSE						
SR	Positive Slew Rate	$V_{OUT} = 1V$ to $4V$, $R_L = 10k\Omega$	-	0.2	-	$V/\mu s$
	Negative Slew Rate		-	0.1	-	$V/\mu s$
t_r, t_f , Small Signal	Rise Time, t_r 10% to 90%	$A_V = +1$, $V_{OUT} = 0.1V_{P-P}$, $R_F = 0\Omega$, $R_L = 10k\Omega$, $C_L = 1.2pF$	-	1.1	-	μs
	Fall Time, t_f 10% to 90%		-	1.1	-	μs
t_r, t_f Large Signal	Rise Time, t_r 10% to 90%	$A_V = +1$, $V_{OUT} = 2V_{P-P}$, $R_F = 0\Omega$, $R_L = 10k\Omega$, $C_L = 1.2pF$	-	20	-	μs
	Fall Time, t_f 10% to 90%		-	30	-	μs
t_s	Settling Time to 0.1%, $2V_{P-P}$ Step	$A_V = +1$, $R_F = 0\Omega$, $R_L = 10k\Omega$, $C_L = 1.2pF$	-	35	-	μs
$t_{recover}$	Output Overload Recovery Time, Recovery to 90% of Output Saturation	$A_V = +2$, $R_F = 10k\Omega$, $R_L = Open$, $C_L = 3.7pF$	-	10.5	-	μs

NOTE:

10. Compliance to datasheet limits is assured by one or more methods: production test, characterization and/or design.

Typical Performance Curves

$V_+ = 5V$, $V_- = 0V$, $V_{CM} = 2.5V$, $R_L = \text{Open}$, $T = +25^\circ\text{C}$, unless otherwise specified.

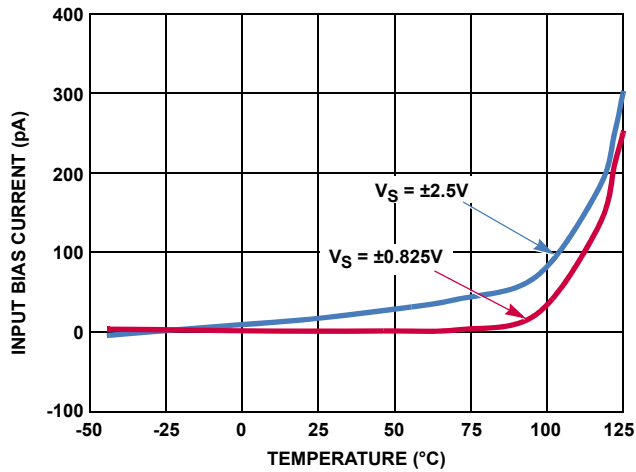


FIGURE 3. I_{B+} vs TEMPERATURE

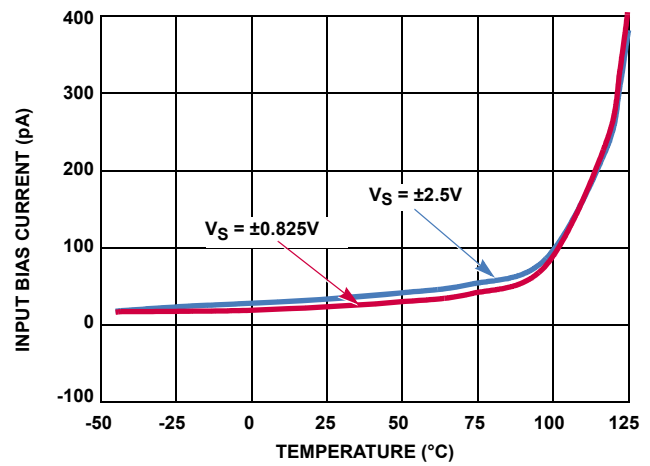


FIGURE 4. I_{B-} vs TEMPERATURE

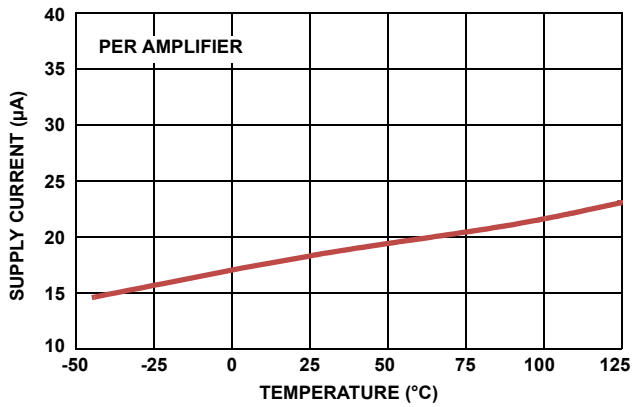


FIGURE 5. SUPPLY CURRENT vs TEMPERATURE, $V_S = \pm 0.825V$

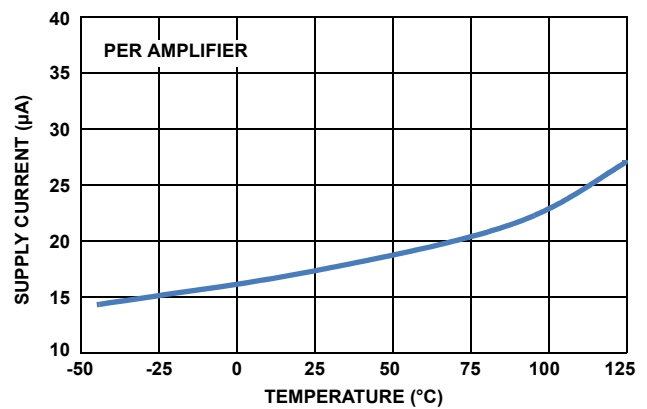


FIGURE 6. SUPPLY CURRENT vs TEMPERATURE, $V_S = \pm 2.5V$

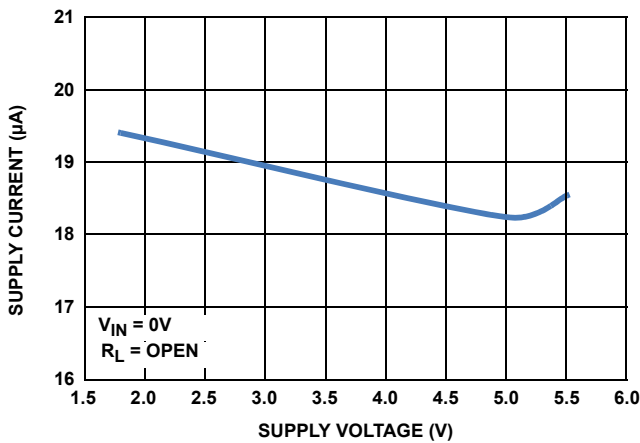


FIGURE 7. SUPPLY CURRENT vs SUPPLY VOLTAGE

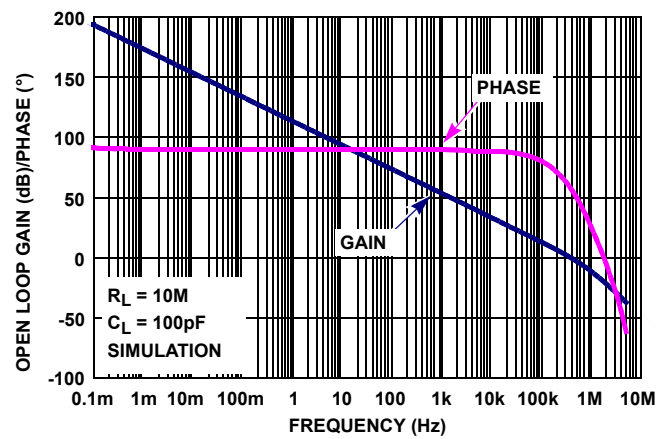


FIGURE 8. FREQUENCY RESPONSE vs OPEN LOOP GAIN, $R_L = 10M\Omega$

Typical Performance Curves

$V_+ = 5V$, $V_- = 0V$, $V_{CM} = 2.5V$, $R_L = \text{Open}$, $T = +25^\circ\text{C}$, unless otherwise specified. (Continued)

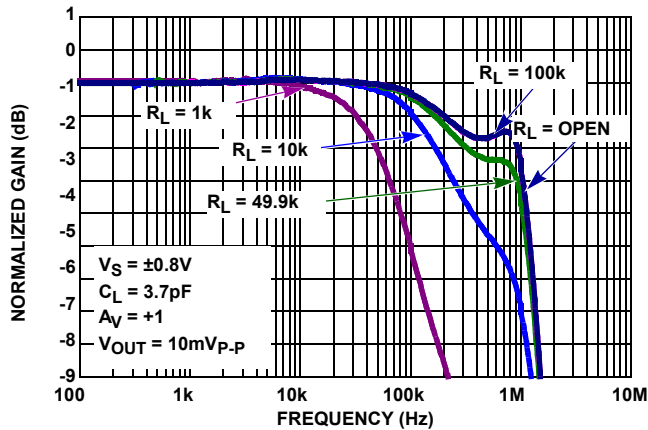


FIGURE 9. GAIN vs FREQUENCY vs R_L , $V_S = \pm 0.8V$

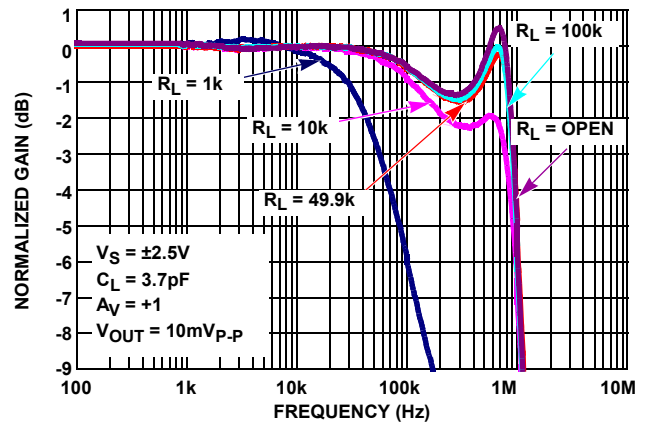


FIGURE 10. GAIN vs FREQUENCY vs R_L , $V_S = \pm 2.5V$

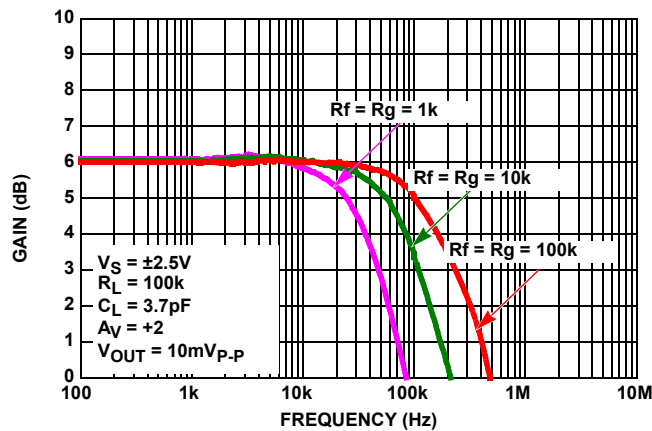


FIGURE 11. GAIN vs FREQUENCY vs FEEDBACK RESISTOR VALUES R_f/R_g

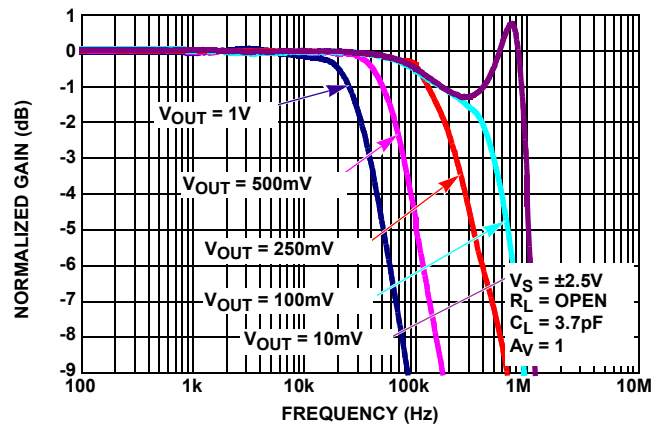


FIGURE 12. GAIN vs FREQUENCY vs V_{OUT}

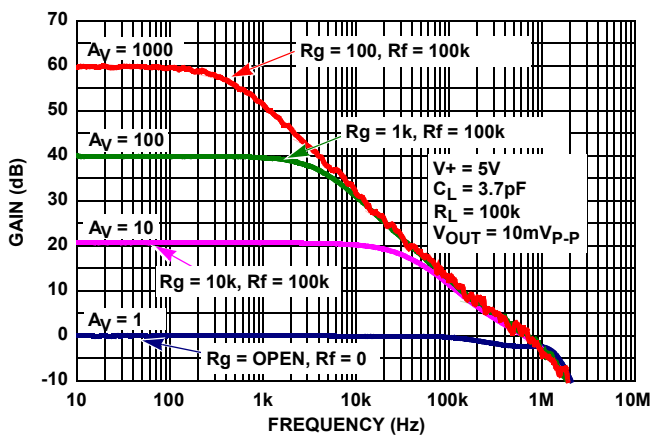


FIGURE 13. FREQUENCY RESPONSE vs CLOSED LOOP GAIN

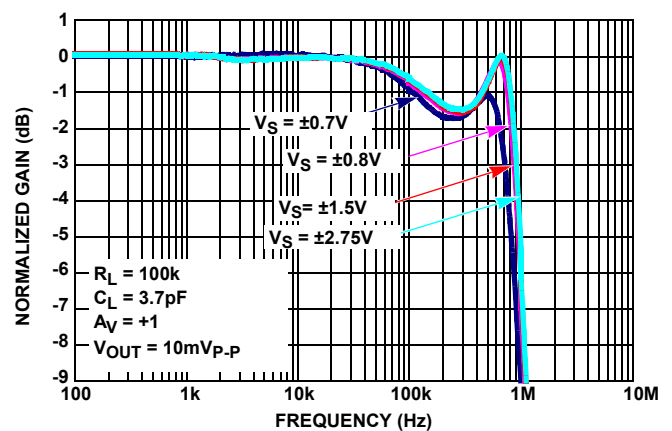


FIGURE 14. GAIN vs FREQUENCY vs SUPPLY VOLTAGE

Typical Performance Curves

$V_+ = 5V$, $V_- = 0V$, $V_{CM} = 2.5V$, $R_L = \text{Open}$, $T = +25^\circ\text{C}$, unless otherwise specified. (Continued)

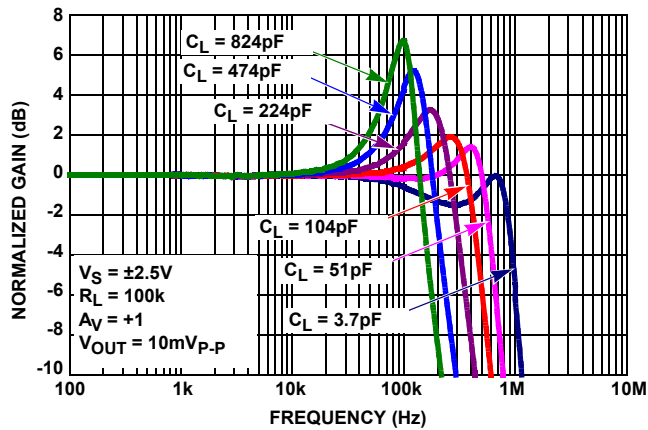


FIGURE 15. GAIN vs FREQUENCY vs C_L

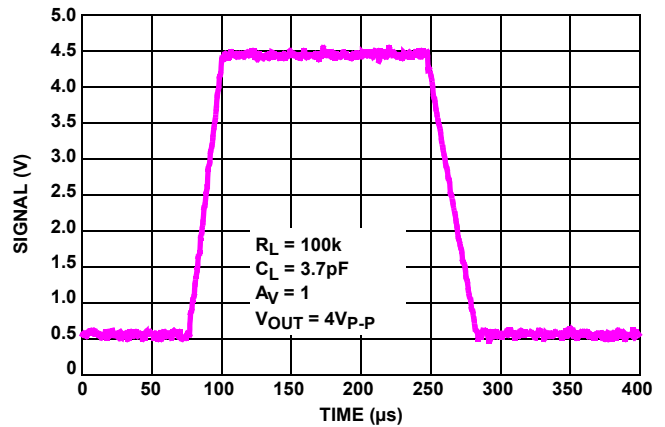


FIGURE 16. LARGE SIGNAL STEP RESPONSE (4V)

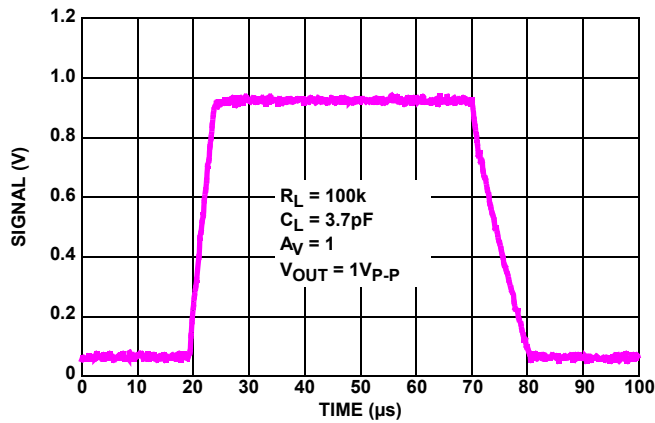


FIGURE 17. LARGE SIGNAL STEP RESPONSE (1V)

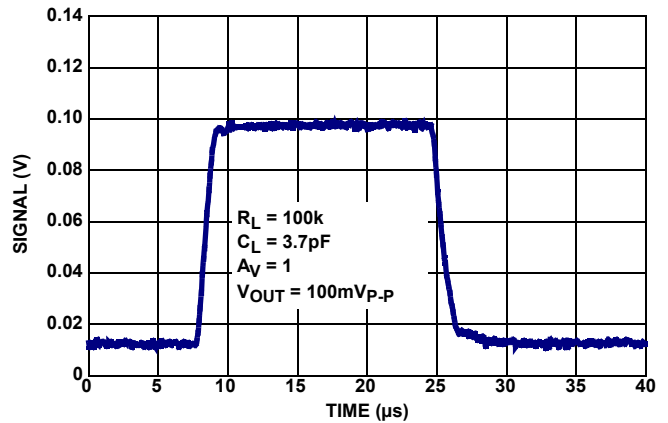


FIGURE 18. SMALL SIGNAL STEP RESPONSE (100mV)

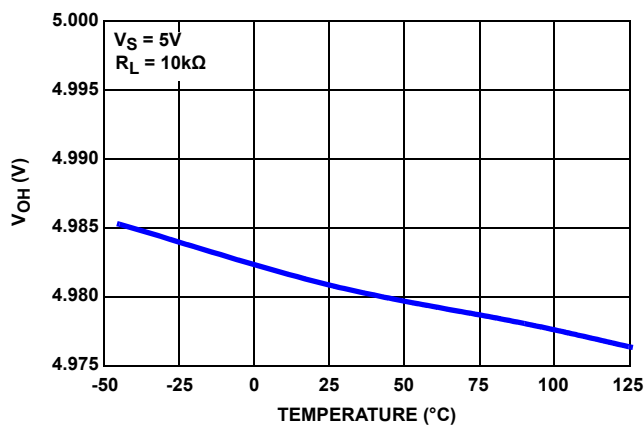


FIGURE 19. V_{OH} vs TEMPERATURE

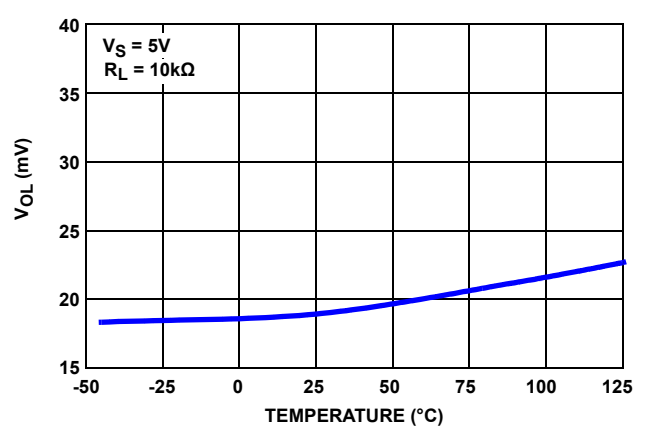


FIGURE 20. V_{OL} vs TEMPERATURE

Typical Performance Curves

$V_+ = 5V$, $V_- = 0V$, $V_{CM} = 2.5V$, $R_L = \text{Open}$, $T = +25^\circ\text{C}$, unless otherwise specified. (Continued)

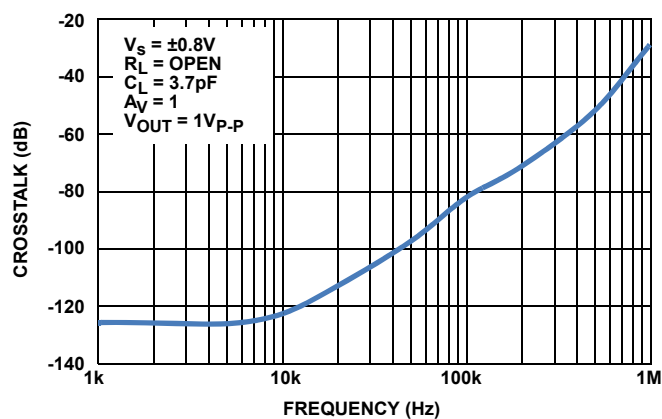


FIGURE 21. CROSSTALK vs FREQUENCY, $V_S = \pm 0.8V$

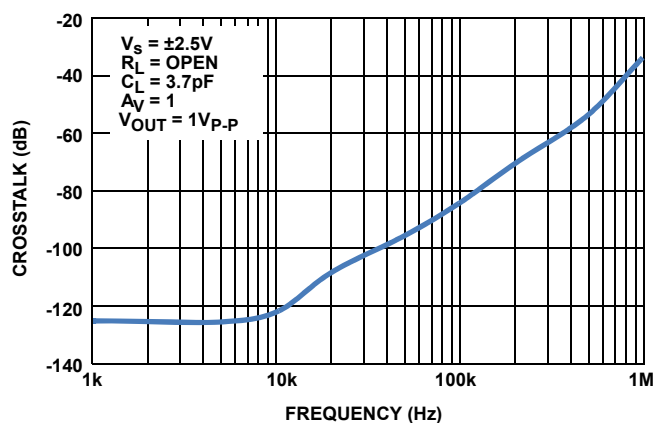


FIGURE 22. CROSSTALK vs FREQUENCY, $V_S = \pm 2.5V$

Applications Information

Functional Description

The ISL28130, ISL28230 and ISL28430 are low offset low drift operational amplifiers with a very high open loop gain (150dB) and rail-to-rail input/output. The ISL28130, ISL28230 and ISL28430 operate on a single supply range of 1.65V to 5.5V or dual supply range of $\pm 0.825\text{V}$ to $\pm 2.75\text{V}$ while consuming only 20 μA of supply current per channel. The ISL28130, ISL28230 and ISL28430 has a 400kHz gain-bandwidth.

The high open loop gain, low offset voltage, high bandwidth and low $1/f$ noise make the ISL28130, ISL28230 and ISL28430 ideal for precision applications.

Rail-to-rail Input and Output (RRIO)

The RRIO CMOS amplifier uses parallel input PMOS and NMOS that enable the inputs to swing 100mV beyond either supply rail. The inverting and non-inverting inputs do not have back-to-back input clamp diodes and are capable of maintaining high input impedance at high differential input voltages. This is effective in eliminating output distortion caused by high slew-rate input signals.

The output stage uses common source connected PMOS and NMOS devices to achieve rail-to-rail output drive capability with 15mA current limit and the capability to swing to within 50mV of either rail while driving a 10k Ω load.

IN+ and IN- Protection

All input terminals have internal ESD protection diodes to both positive and negative supply rails, limiting the input voltage to within one diode beyond the supply rails. For applications where either input is expected to exceed the rails by 0.5V, an external series resistor must be used to ensure the input currents never exceed 20mA (see Figure 23).

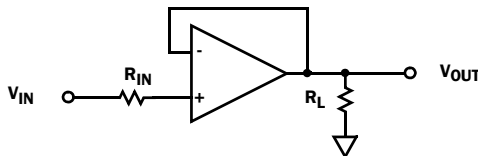


FIGURE 23. INPUT CURRENT LIMITING

Layout Guidelines for High Impedance Inputs

To achieve the maximum performance of the high input impedance and low offset voltage of the ISL28130, ISL28230 and ISL28430 amplifiers, care should be taken in the circuit board layout. The PC board surface must remain clean and free of moisture to avoid leakage currents between adjacent traces. Surface coating of the circuit board will reduce surface moisture and provide a humidity barrier, reducing parasitic resistance on the board.

High Gain, Precision DC-Coupled Amplifier

The circuit in Figure 24 implements a single-stage DC-coupled amplifier with an input DC sensitivity of under 100nV that is only possible using a low VOS amplifier with high open loop gain. High gain DC amplifiers operating from low voltage supplies are not practical using typical low offset precision op amps. For example, a typical precision amplifier in a gain of 10kV/V with a $\pm 100\mu\text{V}$ V_{OS} and offset drift 0.5 $\mu\text{V}/^\circ\text{C}$ of a low offset op amp would produce a DC error of $>1\text{V}$ with an additional 5mV/ $^\circ\text{C}$ of temperature dependent error making it difficult to resolve DC input voltage changes in the mV range.

The $\pm 40\mu\text{V}$ max V_{OS} and 150nV/ $^\circ\text{C}$ of temperature drift of the ISL28130, ISL28230, ISL28430 produces a temperature stable maximum DC output error of only $\pm 400\text{mV}$ with a maximum output temperature drift of 1.5mV/ $^\circ\text{C}$. The additional benefit of a very low $1/f$ noise corner frequency and some feedback filtering enables DC voltages and voltage fluctuations well below 10 μV to be easily detected with a simple single stage amplifier.

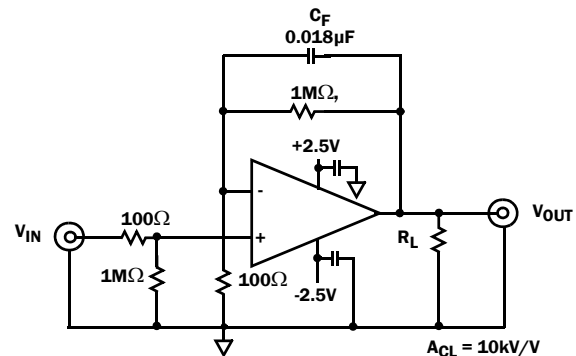


FIGURE 24. HIGH GAIN, PRECISION DC-COUPLED AMPLIFIER

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

DATE	REVISION	CHANGE
3/1/11	FN7623.2	-Ordering Information Table: Removed all 'Coming Soon' under part numbers (except for ISL28130FBZ and ISL28230FRZ), added part markings for all 125 °C grade parts. Added new data column called 'TEMPERATURE GRADE' to distinguish between 'Commercial' and 'Full' temp grades. - Electrical Specifications Table: added new text to common conditions: "Boldface limits apply over the entire operating temperature range". This note allows bold face limits to apply both to commercial and full grade temp devices. - Added over temp 0 °C to 70 °C spec for Vos in addition to -40 °C to 125 °C Vos spec. Original Vos spec of 46.8µV for -40 °C to 125 °C is a typo based on a TCvos of 150nV/C. -40 °C to 125 °C limit corrected as 55µV over temp.
12/7/10	FN7623.1	Corrected Thermals for DFN package in "Tja from 125 to 53, "Tjc from 90 to 12"
12/3/10		Removed Part Markings from Full temp grade parts and changed to TBD until availability is validated.
12/2/10		-Updated copyright to legal's suggested verbiage on page 1. -Updated front page text to add DFN packaging and extended temp range -40 °C to +125 °C -Removed previous Ib vs Temp plot and added new -40 °C to +125 °C Ib vs Temp plot on front page. -Updated ordering information table by adding a full temp range option to all parts and temp range column. Also added in DFN part to ordering table. All full temp parts are stamped Coming Soon. Parts ISL28130CHZ-T7, ISL28130CHZ-T7A and ISL28130CEZ-T7, ISL28130CEZ-T7A shown they are Tape and reel only parts. -Added in DFN package to Pin Configurations table. -Added in -40 °C to +125 °C temp range under Operating Conditions page 5. -Added the testing standards performance information to the ESD ratings in Abs Max Table -Added new Input Bias Current Ib spec of 700pA MIN/MAX in Electrical Spec table for -40 °C to +125 °C temp range -Revised Note 10 for Electrical Spec table as: "Compliance to datasheet limits is assured by one or more methods: production test, characterization and/or design." -Updated all curves in the datasheet with 0 °C to +70 °C temp range to -40 °C to +125 °C temp range. -Added DFN package L8.3x3J outline drawing to the end of datasheet.
10/19/10		On page 6 changed "Supply Current, Per Amplifier" from a typical of 18µA to 20µA to comply with front page.
8/17/10	FN7623.0	Initial Release

Products

Intersil Corporation is a leader in the design and manufacture of high-performance analog semiconductors. The Company's products address some of the industry's fastest growing markets, such as, flat panel displays, cell phones, handheld products, and notebooks. Intersil's product families address power management and analog signal processing functions. Go to www.intersil.com/products for a complete list of Intersil product families.

*For a complete listing of Applications, Related Documentation and Related Parts, please see the respective device information page on intersil.com: [ISL28130](http://www.intersil.com/products), [ISL28230](http://www.intersil.com/products), [ISL28430](http://www.intersil.com/products).

To report errors or suggestions for this datasheet, please go to www.intersil.com/askourstaff

FITs are available from our website at <http://rel.intersil.com/reports/search.php>

For additional products, see www.intersil.com/product_tree

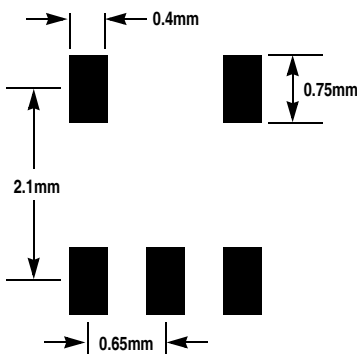
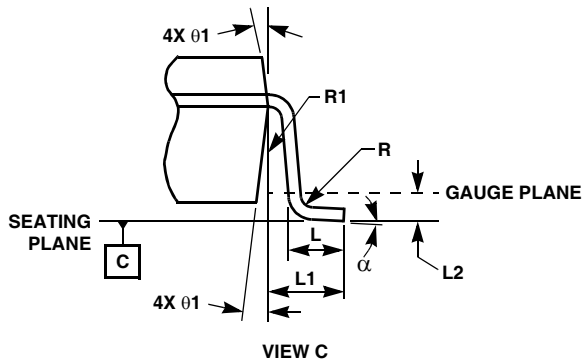
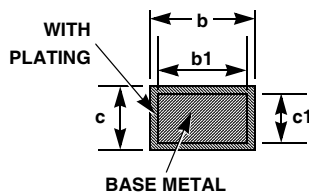
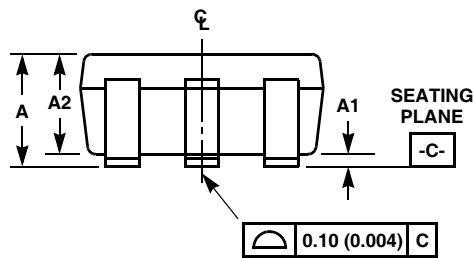
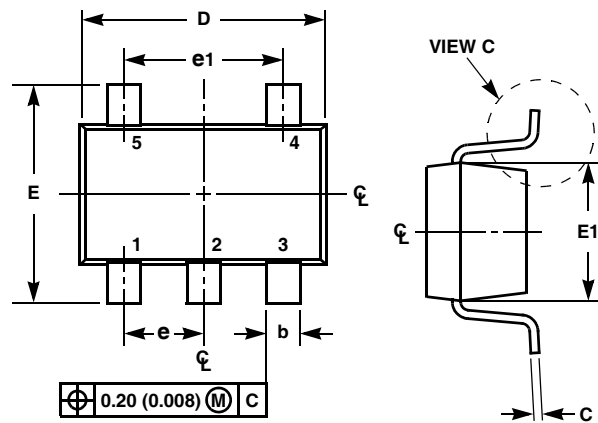
Intersil products are manufactured, assembled and tested utilizing ISO9000 quality systems as noted in the quality certifications found at www.intersil.com/design/quality

Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design, software and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see www.intersil.com

ISL28130, ISL28230, ISL28430

Small Outline Transistor Plastic Packages (SC70-5)



TYPICAL RECOMMENDED LAND PATTERN

P5.049

5 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN	MAX	MIN	MAX	
A	0.031	0.043	0.80	1.10	-
A1	0.000	0.004	0.00	0.10	-
A2	0.031	0.039	0.80	1.00	-
b	0.006	0.012	0.15	0.30	-
b1	0.006	0.010	0.15	0.25	-
c	0.003	0.009	0.08	0.22	6
c1	0.003	0.009	0.08	0.20	6
D	0.073	0.085	1.85	2.15	3
E	0.071	0.094	1.80	2.40	-
E1	0.045	0.053	1.15	1.35	3
e	0.0256 Ref		0.65 Ref		-
e1	0.0512 Ref		1.30 Ref		-
L	0.010	0.018	0.26	0.46	4
L1	0.017 Ref.		0.420 Ref.		-
L2	0.006 BSC		0.15 BSC		-
α	0°	8°	0°	8°	-
N	5		5		5
R	0.004	-	0.10	-	-
R1	0.004	0.010	0.15	0.25	-

Rev. 3 7/07

NOTES:

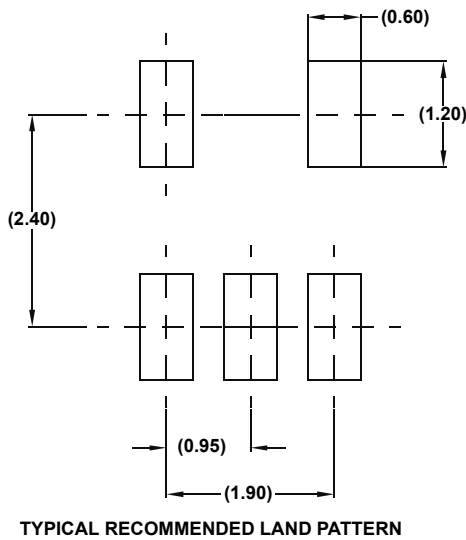
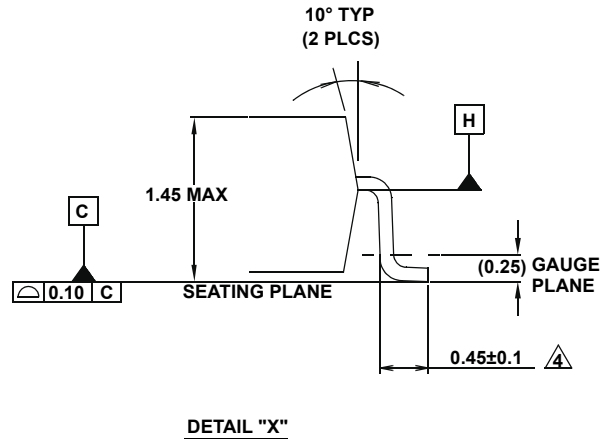
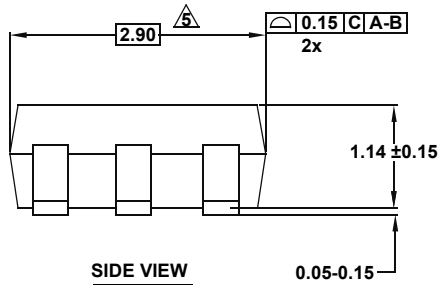
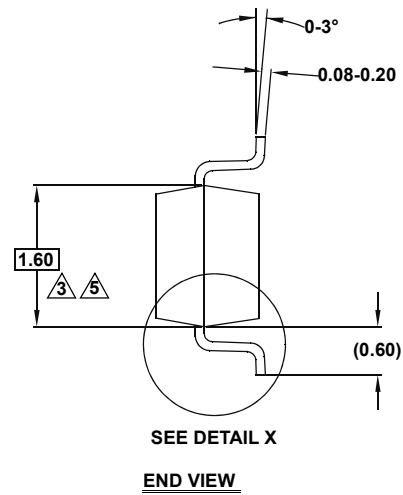
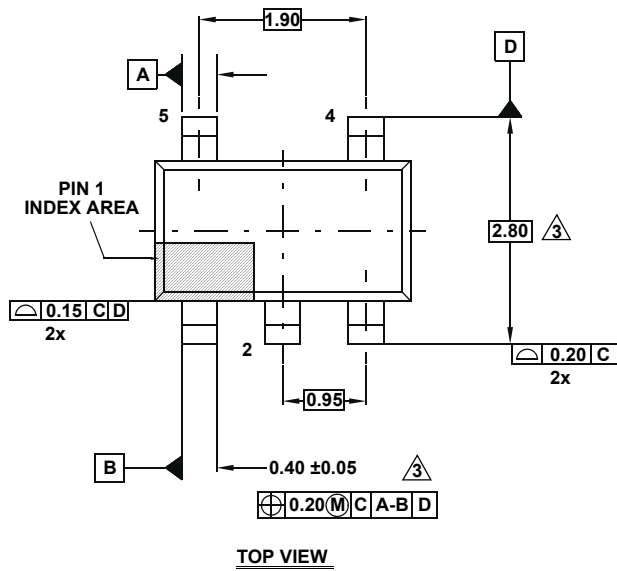
1. Dimensioning and tolerances per ASME Y14.5M-1994.
2. Package conforms to EIAJ SC70 and JEDEC MO-203AA.
3. Dimensions D and E1 are exclusive of mold flash, protrusions, or gate burrs.
4. Footlength L measured at reference to gauge plane.
5. "N" is the number of terminal positions.
6. These Dimensions apply to the flat section of the lead between 0.08mm and 0.15mm from the lead tip.
7. Controlling dimension: MILLIMETER. Converted inch dimensions are for reference only.

Package Outline Drawing

P5.064A

5 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE

Rev 0, 2/10



NOTES:

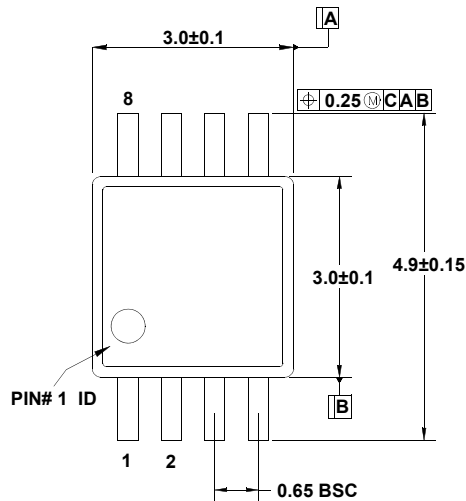
1. Dimensions are in millimeters.
Dimensions in () for Reference Only.
2. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
3. Dimension is exclusive of mold flash, protrusions or gate burrs.
4. Foot length is measured at reference to gauge plane.
5. This dimension is measured at Datum "H".
6. Package conforms to JEDEC MO-178AA.

Package Outline Drawing

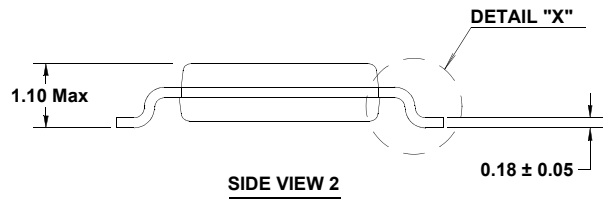
M8.118A

8 LEAD MINI SMALL OUTLINE PLASTIC PACKAGE (MSOP)

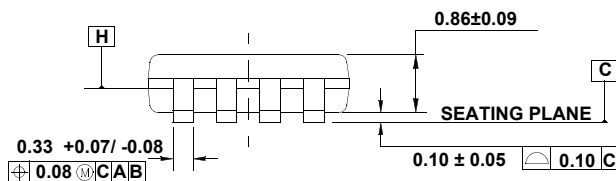
Rev 0, 9/09



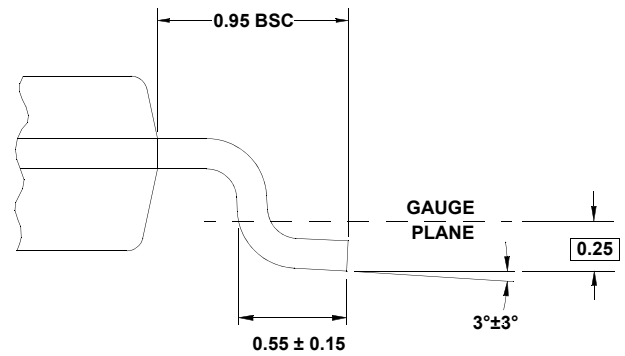
TOP VIEW



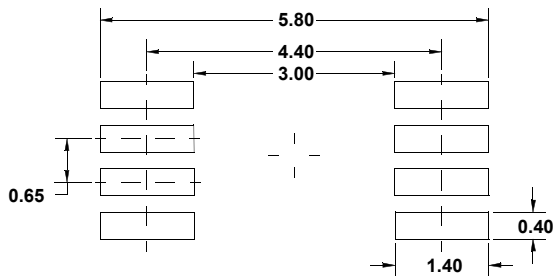
SIDE VIEW 2



SIDE VIEW 1



DETAIL "X"



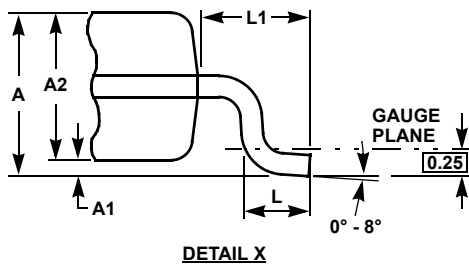
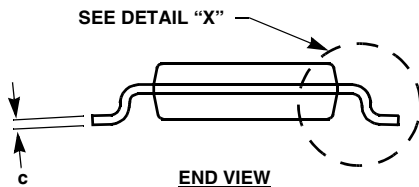
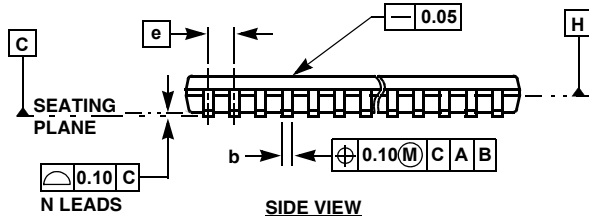
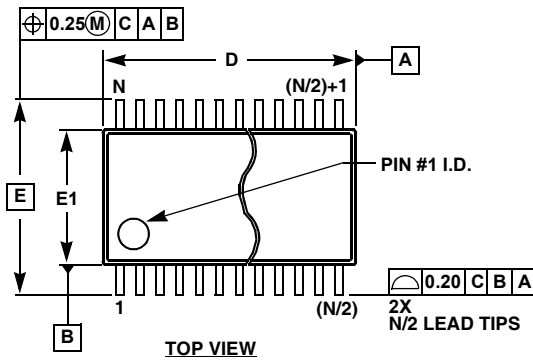
TYPICAL RECOMMENDED LAND PATTERN

NOTES:

1. Dimensions are in millimeters.
2. Dimensioning and tolerancing conform to JEDEC MO-187-AA and AMSE Y14.5m-1994.
3. Plastic or metal protrusions of 0.15mm max per side are not included.
4. Plastic interlead protrusions of 0.25mm max per side are not included.
5. Dimensions "D" and "E1" are measured at Datum Plane "H".
6. This replaces existing drawing # MDP0043 MSOP 8L.

ISL28130, ISL28230, ISL28430

Thin Shrink Small Outline Package Family (TSSOP)



MDP0044

THIN SHRINK SMALL OUTLINE PACKAGE FAMILY

SYMBOL	MILLIMETERS					TOLERANCE
	14 LD	16 LD	20 LD	24 LD	28 LD	
A	1.20	1.20	1.20	1.20	1.20	Max
A1	0.10	0.10	0.10	0.10	0.10	±0.05
A2	0.90	0.90	0.90	0.90	0.90	±0.05
b	0.25	0.25	0.25	0.25	0.25	+0.05/-0.06
c	0.15	0.15	0.15	0.15	0.15	+0.05/-0.06
D	5.00	5.00	6.50	7.80	9.70	±0.10
E	6.40	6.40	6.40	6.40	6.40	Basic
E1	4.40	4.40	4.40	4.40	4.40	±0.10
e	0.65	0.65	0.65	0.65	0.65	Basic
L	0.60	0.60	0.60	0.60	0.60	±0.15
L1	1.00	1.00	1.00	1.00	1.00	Reference

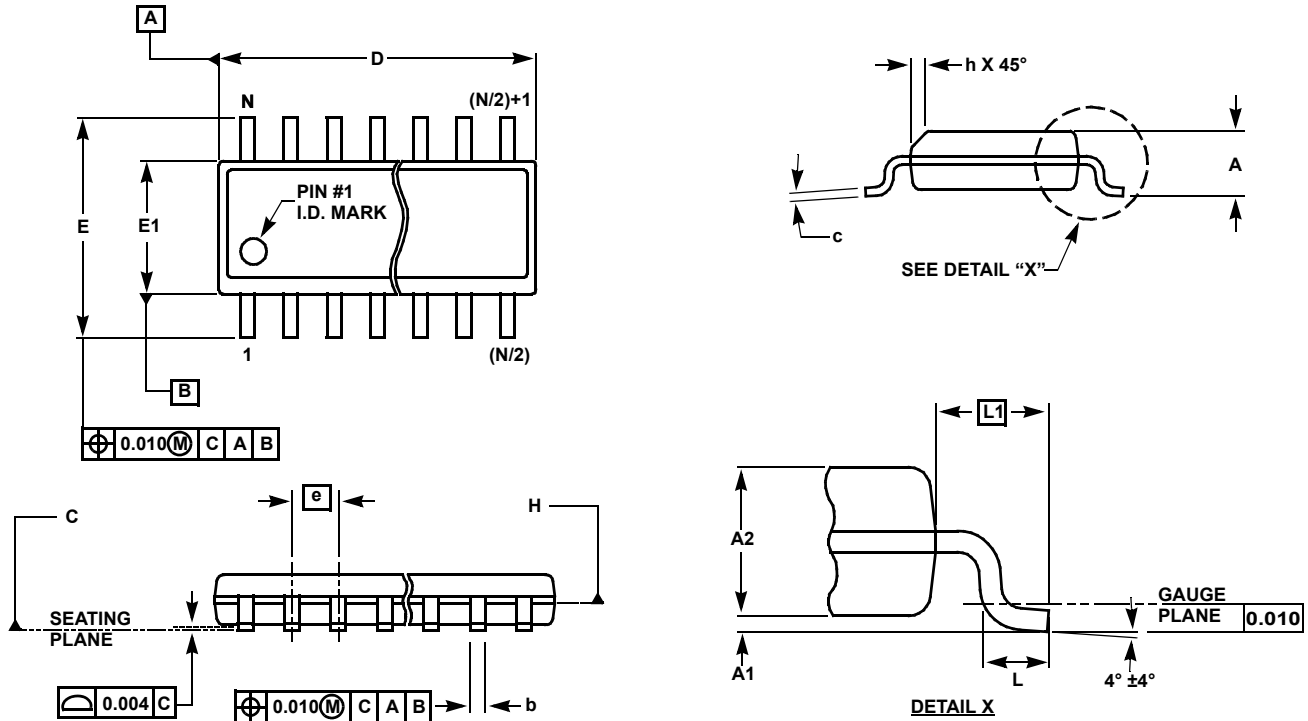
Rev. F 2/07

NOTES:

1. Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15mm per side.
2. Dimension "E1" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm per side.
3. Dimensions "D" and "E1" are measured at dAtum Plane H.
4. Dimensioning and tolerancing per ASME Y14.5M-1994.

ISL28130, ISL28230, ISL28430

Small Outline Package Family (SO)



MDP0027

SMALL OUTLINE PACKAGE FAMILY (SO)

SYMBOL	INCHES							TOLERANCE	NOTES
	SO-8	SO-14	SO16 (0.150")	SO16 (0.300") (SOL-16)	SO20 (SOL-20)	SO24 (SOL-24)	SO28 (SOL-28)		
A	0.068	0.068	0.068	0.104	0.104	0.104	0.104	MAX	-
A1	0.006	0.006	0.006	0.007	0.007	0.007	0.007	±0.003	-
A2	0.057	0.057	0.057	0.092	0.092	0.092	0.092	±0.002	-
b	0.017	0.017	0.017	0.017	0.017	0.017	0.017	±0.003	-
c	0.009	0.009	0.009	0.011	0.011	0.011	0.011	±0.001	-
D	0.193	0.341	0.390	0.406	0.504	0.606	0.704	±0.004	1, 3
E	0.236	0.236	0.236	0.406	0.406	0.406	0.406	±0.008	-
E1	0.154	0.154	0.154	0.295	0.295	0.295	0.295	±0.004	2, 3
e	0.050	0.050	0.050	0.050	0.050	0.050	0.050	Basic	-
L	0.025	0.025	0.025	0.030	0.030	0.030	0.030	±0.009	-
L1	0.041	0.041	0.041	0.056	0.056	0.056	0.056	Basic	-
h	0.013	0.013	0.013	0.020	0.020	0.020	0.020	Reference	-
N	8	14	16	16	20	24	28	Reference	-

Rev. M 2/07

NOTES:

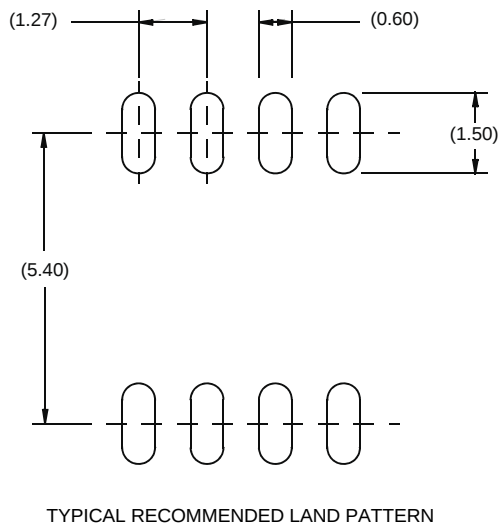
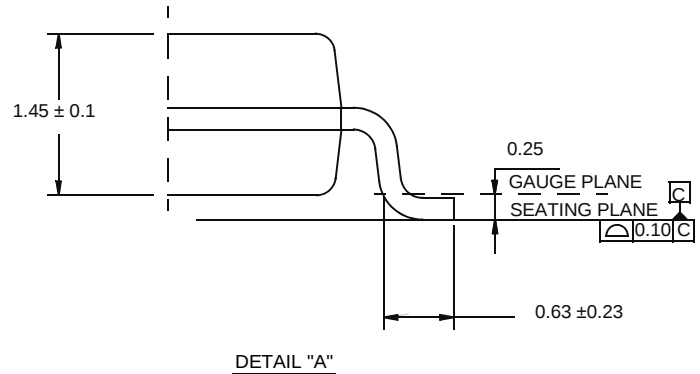
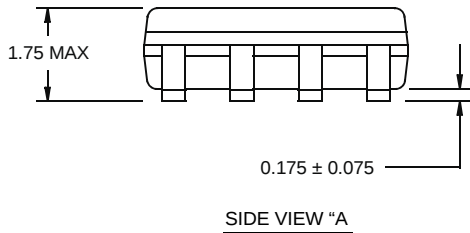
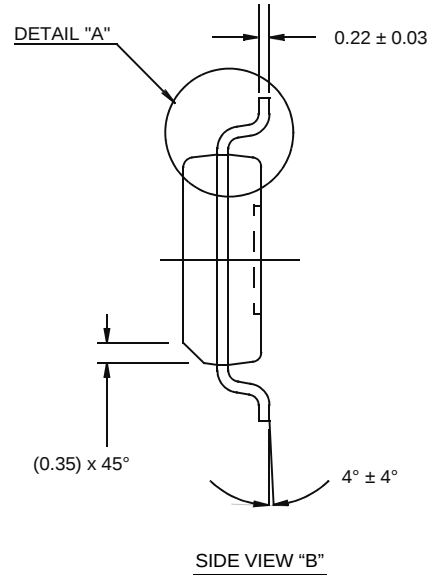
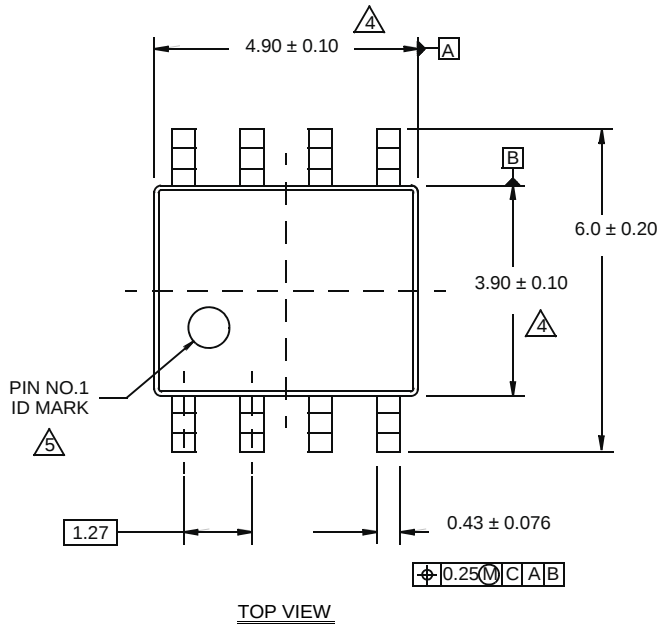
1. Plastic or metal protrusions of 0.006" maximum per side are not included.
2. Plastic interlead protrusions of 0.010" maximum per side are not included.
3. Dimensions "D" and "E1" are measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994

Package Outline Drawing

M8.15E

8 LEAD NARROW BODY SMALL OUTLINE PLASTIC PACKAGE

Rev 0, 08/09



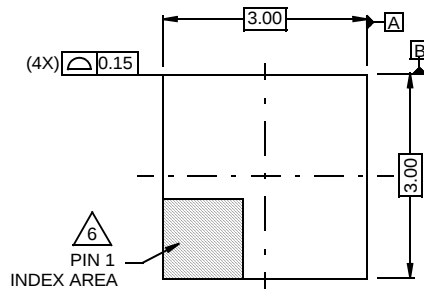
NOTES:

1. Dimensions are in millimeters.
Dimensions in () for Reference Only.
2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
3. Unless otherwise specified, tolerance : Decimal ± 0.05
4. Dimension does not include interlead flash or protrusions.
Interlead flash or protrusions shall not exceed 0.25mm per side.
5. The pin #1 identifier may be either a mold or mark feature.
6. Reference to JEDEC MS-012.

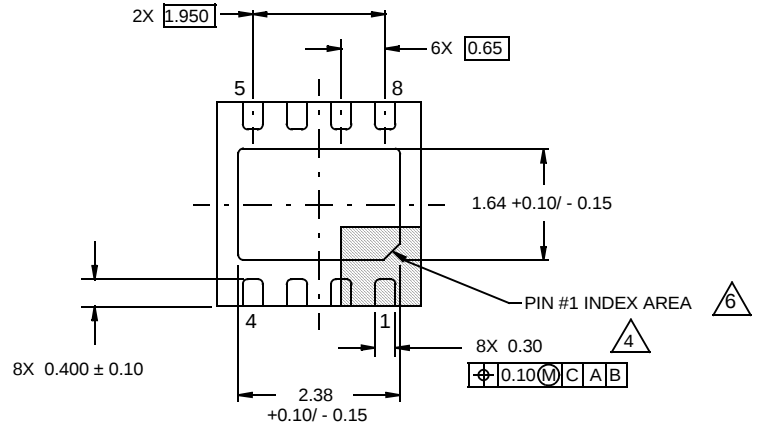
Package Outline Drawing L8.3x3J

8 LEAD DUAL FLAT NO-LEAD PLASTIC PACKAGE

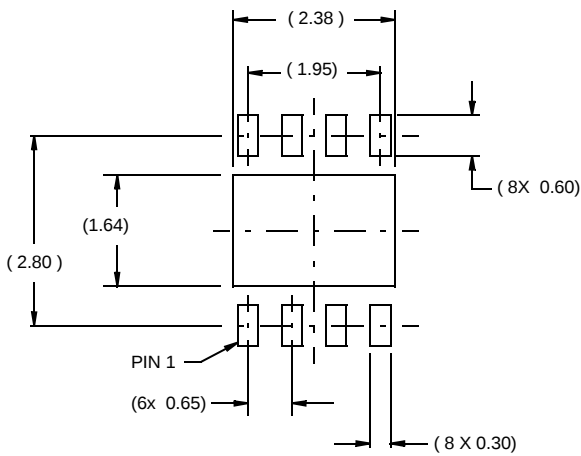
Rev 0 9/09



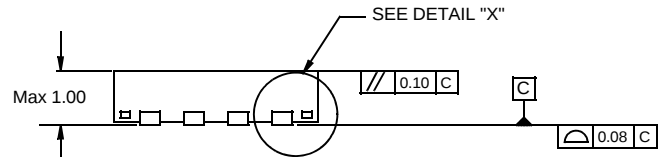
TOP VIEW



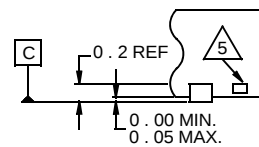
BOTTOM VIEW



TYPICAL RECOMMENDED LAND PATTERN



SIDE VIEW



DETAIL "X"

NOTES:

1. Dimensions are in millimeters.
Dimensions in () for Reference Only.
2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
3. Unless otherwise specified, tolerance : Decimal ± 0.05
4. Dimension applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
5. Tiebar shown (if present) is a non-functional feature.
6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.